Room-Temperature Quantum Hall Effect in Graphene

K. S. Novoselov, ¹ Z. Jiang, ^{2,3} Y. Zhang, ² S. V. Morozov, ¹ H. L. Stormer, ² U. Zeitler, ⁴ J. C. Maan, ⁴ G. S. Boebinger, ³ P. Kim, ²* A. K. Geim ¹*

he quantum Hall effect (QHE), one example of a quantum phenomenon that occurs on a truly macroscopic scale, has been attracting intense interest since its discovery in 1980 (1). The QHE, exclusive to two-dimensional (2D) metals, has elucidated many important aspects of quantum physics and has deepened our understanding of interacting systems. It has also led to the establishment of a new metrological standard, the resistance quantum, h/e^2 , that contains only fundamental constants of the electron charge, e, and Planck's constant, h(2). As with many other quantum phenomena, the observation of the QHE usually requires low temperatures, typically below the boiling point of liquid helium (1). Efforts to extend the QHE temper-

ature range by, for example, using semiconductors with small effective masses of charge carriers have so far failed to reach temperatures above 30 K (3, 4). These efforts are driven by both an innate desire to observe apparently fragile quantum phenomena under ambient conditions and the pragmatic need to perform metrology at room, or at least liquid-nitrogen, temperatures. More robust quantum states, implied by their persistence to higher temperatures, would also provide added freedom to investigate finer features of the QHE and, possibly, allow higher quantization accuracy (2). We show that in graphene, a single layer of carbon atoms tightly packed in a honeycomb crystal lattice, the QHE can be observed even at room temperature. This is due to the highly unusual nature of charge carriers in graphene, which behave as massless relativistic particles (Dirac fermions) and move with little scattering under ambient conditions (5, 6).

Figure 1A shows one of our devices used in the QHE measurements. At room temperature, its Hall conductivity, σ_{xy} , reveals plateaus at $2e^2/h$ for both electrons and holes, while the longitudinal conductivity, ρ_{xx} , approaches zero (<10 ohms) exhibiting an activation energy $\Delta E \approx 600$ K

(Fig. 1B). The quantization in σ_{xy} is exact within an experimental accuracy $\approx 0.2\%$ (Fig. 1C). The survival of the QHE to such high temperatures can be attributed to the large cyclotron gaps, $\hbar\omega_{c}$, characteristic to Dirac fermions in graphene. Their energy quantization in a magnetic field, B, is described by $E_N = v_F \sqrt{|2e\hbar BN|}$, where $v_F \approx 10^6$ m s^{-1} is the Fermi velocity and N an integer Landau level (LL) number (5, 6). The expression yields an energy gap $\Delta E \approx 2800 \text{ K}$ at B = 45 Tif the Fermi energy, $E_{\rm F}$, lies between the lowest LL, N = 0, and the first excited one, $N = \pm 1$ (Fig. 1B, inset). This implies that, in our experiments at room temperature, $\hbar\omega_c$ exceeded the thermal energy, $k_{\rm B}T$, by a factor of 10. In addition to the large $\hbar\omega_c$, there are a number of other factors that help the QHE in graphene to survive

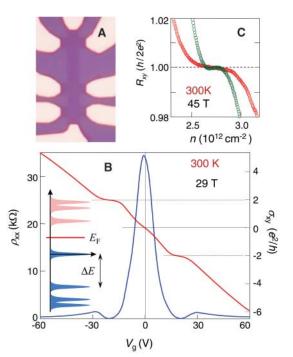


Fig. 1. Room-temperature QHE in graphene. **(A)** Optical micrograph of one of the devices used in the measurements. The scale is given by the Hall bar's width of 2 μm. Device fabrication procedures were described in (*5*). **(B)** σ_{xy} (red) and ρ_{xx} (blue) as a function of gate voltages (V_g) in a magnetic field of 29 T. Positive values of V_g induce electrons, and negative values of V_g induce holes, in concentrations $n = (7.2 \times 10^{10} \text{ cm}^{-2} \text{ V}^{-1})V_g$ (*5*, *6*). (Inset) The LL quantization for Dirac fermions. **(C)** Hall resistance, R_{xy} , for electrons (red) and holes (green) shows the accuracy of the observed quantization at 45 T.

to such high temperatures. First, graphene devices allow for very high carrier concentrations (up to $10^{13}~{\rm cm}^{-2}$) with only a single 2D subband occupied, which is essential to fully populate the lowest LL even in ultra-high B. This is in contrast to traditional 2D systems (for example, GaAs heterostructures), which are either depopulated already in moderate B or exhibit multiple subband occupation, leading to the reduction of the effective energy gap to values well below $\hbar\omega_c$. Second, the mobility, μ , of Dirac fermions in our samples does not change appreciably from liquid-helium to room temperature. It remains at $\approx 10,000~{\rm cm}^2~{\rm V}^{-1}~{\rm s}^{-1}$, which yields a scattering time of $\tau \sim 10^{-13}~{\rm s}$ so that the high field limit $\omega_c \tau = \mu \cdot B >> 1$ is reached in fields of several T.

These characteristics of graphene foster hopes for the room-temperature QHE observable in fields substantially smaller than 30 T. In fact, we observed the Hall plateaus developing already in B < 20 T at 300 K. The need for high B is attributed to broadened LLs caused by disorder, which reduces the activation energy. We expect that improving sample homogeneity and achieving higher μ (currently limited by static defects) should allow the observation of the roomtemperature QHE by using conventional magnets. This should open up new vistas for developing graphene-based resistance standards (certainly, operational above liquid-nitrogen temperature) and for novel quantum devices working at elevated temperatures.

References and Notes

- 1. S. Das Sarma, A. Pinczuk, *Perspectives in Quantum Hall Effects* (Wiley, New York, 1997).
- B. Jeckelmann, B. Jeanneret, Rep. Prog. Phys. 64, 1603 (2001).
- 3. S. Q. Murphy et al., Physica E (Amsterdam) **6**, 293 (2000).
- 4. G. Landwehr et al., Physica E (Amsterdam) 6, 713 (2000).
- 5. K. S. Novoselov et al., Nature 438, 197 (2005).
- Y. Zhang, Y. W. Tan, H. L. Stormer, P. Kim, Nature 438, 201 (2005).
- 7. This work was supported by Engineering and Physical Sciences Research Council (UK), NSF (DMR-03-52738), EuroMagNet (EU RII3-CT-2004-506239), U.S. Department of Energy (DOE) (DE-AIO2-04ER46133 and DE-FG02-05ER4615), the Royal Society, Leverholme Trust, Microsoft Corporation, and W. M. Keck Foundation. The experiments were partially performed at the National High Magnetic Field Laboratory (supported by NSF cooperative agreement no. DMR-0084173, by the state of Florida, and by the DOE) and the Netherlands High Field Magnet Laboratory (supported by the Foundation for Fundamental Research on Matter and the EU).

6 November 2006; accepted 31 January 2007 Published online 15 February 2007; 10.1126/science.1137201 Include this information when citing this paper.

¹Department of Physics, University of Manchester, Manchester M13 9PL, UK. ²Department of Physics, Columbia University, New York, NY 10027, USA. ³National High Magnetic Field Laboratory, Tallahassee, FL 32310, USA. ⁴High Field Magnet Laboratory, Radboud University Nijmegen, 6525 ED Nijmegen, Netherlands.

*To whom correspondence should be addressed. E-mail: pkim@phys.columbia.edu (P.K.); geim@man.ac.uk (A.K.G.)